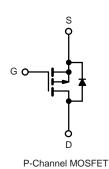


# ZXMP3F30FHTA-VB Datasheet

# P-Channel 30 V (D-S) MOSFET

| PRODUCT SUMMARY     |                                    |                                 |                       |  |  |
|---------------------|------------------------------------|---------------------------------|-----------------------|--|--|
| V <sub>DS</sub> (V) | $R_{DS(on)}$ ( $\Omega$ ) Typ.     | I <sub>D</sub> (A) <sup>a</sup> | Q <sub>g</sub> (Typ.) |  |  |
|                     | 0.046 at V <sub>GS</sub> = - 10 V  | - 5.6                           |                       |  |  |
| - 30                | 0.049 at V <sub>GS</sub> = - 6 V   | - 5                             | 11.4 nC               |  |  |
|                     | 0.054 at V <sub>GS</sub> = - 4.5 V | -4.5                            |                       |  |  |





- For Mobile Computing
  - Load Switch
  - Notebook Adaptor Switch
  - DC/DC Converter

| F | EATURES                     |                   |
|---|-----------------------------|-------------------|
| • | TrenchFET® Power MOSFET     | (Pb)              |
| • | 100 % R <sub>q</sub> Tested | Pb-free           |
|   |                             |                   |
|   | 3                           | RoHS              |
|   | 3                           | RoHS<br>COMPLIANT |

| Parameter                                          |                        | Symbol                            | Limit                | Unit |  |
|----------------------------------------------------|------------------------|-----------------------------------|----------------------|------|--|
| Drain-Source Voltage                               |                        | V <sub>DS</sub>                   | - 30                 | V    |  |
| Gate-Source Voltage                                |                        | V <sub>GS</sub>                   | ± 20                 | V    |  |
|                                                    | T <sub>C</sub> = 25 °C |                                   | - 5.6                |      |  |
| Continuous Drain Correct (T. 450 9C)               | T <sub>C</sub> = 70 °C | 1 . [                             | - 5.1                |      |  |
| Continuous Drain Current (T <sub>J</sub> = 150 °C) | T <sub>A</sub> = 25 °C |                                   | - 5.4 <sup>b,c</sup> |      |  |
|                                                    | T <sub>A</sub> = 70 °C | 1                                 | - 4.3 <sup>b,c</sup> | A    |  |
| Pulsed Drain Current (t = 100 µs)                  |                        | I <sub>DM</sub>                   | - 18                 |      |  |
| Continous Source-Drain Diode Current               | T <sub>C</sub> = 25 °C |                                   | - 2.1                |      |  |
|                                                    | T <sub>A</sub> = 25 °C | l <sub>S</sub>                    | - 1 <sup>b,c</sup>   |      |  |
| Maximum Power Dissipation                          | T <sub>C</sub> = 25 °C |                                   | 2.5                  |      |  |
|                                                    | T <sub>C</sub> = 70 °C | 1 , [                             | 1.6                  | W    |  |
|                                                    | T <sub>A</sub> = 25 °C | P <sub>D</sub>                    | 1.25 <sup>b,c</sup>  | VV   |  |
|                                                    | T <sub>A</sub> = 70 °C | 1                                 | 0.8 <sup>b,c</sup>   |      |  |
| Operating Junction and Storage Temperature Range   |                        | T <sub>J</sub> , T <sub>stq</sub> | - 55 to 150          | °C   |  |

| THERMAL RESISTANCE RATINGS                 |              |                   |         |      |        |  |
|--------------------------------------------|--------------|-------------------|---------|------|--------|--|
| Parameter                                  | Symbol       | Typical           | Maximum | Unit |        |  |
| Maximum Junction-to-Ambient <sup>b,d</sup> | t ≤ 5 s      | R <sub>thJA</sub> | 75      | 100  | °C/W   |  |
| Maximum Junction-to-Foot (Drain)           | Steady State | R <sub>thJF</sub> | 40      | 50   | - C/VV |  |

#### Notes:

- a. Based on  $T_C$  = 25 °C. b. Surface mounted on 1" x 1" FR4 board.
- c. t = 5 s.
- d. Maximum under steady state conditions is 166 °C/W.



| Parameter                                     | Symbol                    | Test Conditions                                                                              | Min.  | Тур.  | Max.     | Unit     |  |
|-----------------------------------------------|---------------------------|----------------------------------------------------------------------------------------------|-------|-------|----------|----------|--|
| Static                                        | ·                         |                                                                                              |       |       |          |          |  |
| Drain-Source Breakdown Voltage                | V <sub>DS</sub>           | $V_{GS} = 0 \text{ V, } I_D = -250  \mu\text{A}$                                             | - 30  |       |          | V        |  |
| V <sub>DS</sub> Temperature Coefficient       | $\Delta V_{DS}/T_{J}$     | J 252A                                                                                       |       | - 19  |          | mV/°C    |  |
| V <sub>GS(th)</sub> Temperature Coefficient   | $\Delta V_{GS(th)}/T_{J}$ | I <sub>D</sub> = - 250 μA                                                                    |       | 4     |          |          |  |
| Gate-Source Threshold Voltage                 | V <sub>GS(th)</sub>       | $V_{DS} = V_{GS}$ , $I_{D} = -250 \mu\text{A}$                                               | - 0.5 |       | - 2.0    | V        |  |
| Gate-Source Leakage                           | I <sub>GSS</sub>          | $V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$                                            |       |       | ± 100    | nA       |  |
|                                               | I <sub>DSS</sub>          | V <sub>DS</sub> = - 30 V, V <sub>GS</sub> = 0 V                                              |       |       | - 1      |          |  |
| Zero Gate Voltage Drain Current               |                           | V <sub>DS</sub> = - 30 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 55 °C                      |       |       | - 5      | μA       |  |
| On-State Drain Current <sup>a</sup>           | I <sub>D(on)</sub>        | $V_{DS} \le -5 \text{ V}, V_{GS} = -10 \text{ V}$                                            | - 2.5 |       |          | Α        |  |
|                                               | . ,                       | V <sub>GS</sub> =- 10 V, I <sub>D</sub> = - 4.4 A                                            |       | 0.046 |          |          |  |
| Drain-Source On-State Resistance <sup>a</sup> | R <sub>DS(on)</sub>       | V <sub>GS</sub> =- 6 V, I <sub>D</sub> = - 4 A                                               |       | 0.049 |          | Ω        |  |
|                                               | , ,                       | V <sub>GS</sub> =- 4.5 V, I <sub>D</sub> = - 3.6 A                                           |       | 0.054 |          |          |  |
| Forward Transconductance <sup>a</sup>         | 9 <sub>fs</sub>           | V <sub>DS</sub> = - 15 V, I <sub>D</sub> = - 3.4 A                                           |       | 18    |          | S        |  |
| Dynamic <sup>b</sup>                          |                           |                                                                                              |       | !     |          |          |  |
| Input Capacitance                             | C <sub>iss</sub>          |                                                                                              |       | 1295  |          |          |  |
| Output Capacitance                            | C <sub>oss</sub>          | V <sub>DS</sub> = - 15 V, V <sub>GS</sub> = 0 V, f = 1 MHz                                   |       | 150   |          | pF       |  |
| Reverse Transfer Capacitance                  | C <sub>rss</sub>          |                                                                                              |       | 130   |          |          |  |
| Table Oats Observe                            |                           | V <sub>DS</sub> = - 15 V, V <sub>GS</sub> = - 10 V, I <sub>D</sub> = - 5.4 A                 |       | 24    | 36       | <u> </u> |  |
| Total Gate Charge                             | $Q_g$                     | D3 - 7 G3 - 7 D -                                                                            |       | 11.4  | 17       | nC       |  |
| Gate-Source Charge                            | Q <sub>gs</sub>           | V <sub>DS</sub> = - 15 V, V <sub>GS</sub> = - 4.5 V, I <sub>D</sub> = - 5.4 A                |       | 3.4   |          |          |  |
| Gate-Drain Charge                             | Q <sub>gd</sub>           | 1                                                                                            |       | 3.8   |          |          |  |
| Gate Resistance                               | $R_g$                     | f = 1 MHz                                                                                    | 1.5   | 7.7   | 15.4     | Ω        |  |
| Turn-On Delay Time                            | t <sub>d(on)</sub>        |                                                                                              |       | 13    | 20       |          |  |
| Rise Time                                     | t <sub>r</sub>            | $V_{DD} = -15 \text{ V}, R_{L} = 3.5 \Omega$                                                 |       | 4     | 8        | 1        |  |
| Turn-Off Delay Time                           | t <sub>d(off)</sub>       | $I_D \cong -4.3 \text{ A}, V_{GEN} = -10 \text{ V}, R_g = 1 \Omega$                          |       | 38    | 57       | -        |  |
| Fall Time                                     | t <sub>f</sub>            | 1                                                                                            |       | 6     | 12       | 1        |  |
| Turn-On Delay Time                            | t <sub>d(on)</sub>        |                                                                                              |       | 28    | 42       | ns       |  |
| Rise Time                                     | t <sub>r</sub>            | $V_{DD} = -15 \text{ V, R}_{L} = 3.5 \Omega$                                                 |       | 16    | 24       |          |  |
| Turn-Off Delay Time                           | t <sub>d(off)</sub>       | $I_D \cong -4.3 \text{ A}, V_{GEN} = -4.5 \text{ V}, R_g = 1 \Omega$                         |       | 30    | 45       |          |  |
| Fall Time                                     | t <sub>f</sub>            | 1                                                                                            |       | 10    | 20       |          |  |
| <b>Drain-Source Body Diode Characteristic</b> | s ·                       |                                                                                              |       | l     | l        |          |  |
| Continuous Source-Drain Diode Current         | Is                        | T <sub>C</sub> = 25 °C                                                                       |       |       | - 2.1    |          |  |
| Pulse Diode Forward Current (t = 100 μs)      | I <sub>SM</sub>           |                                                                                              |       |       | - 80     | A        |  |
| Body Diode Voltage                            | V <sub>SD</sub>           | I <sub>S</sub> = - 4.3 A, V <sub>GS</sub> = 0 V                                              |       | - 0.8 | - 1.2    | V        |  |
| Body Diode Reverse Recovery Time              | t <sub>rr</sub>           |                                                                                              |       | 15    | 23       | ns       |  |
| Body Diode Reverse Recovery Charge            | Q <sub>rr</sub>           | 1                                                                                            |       | 7     | 14       | nC       |  |
| Reverse Recovery Fall Time                    | t <sub>a</sub>            | $I_F = -4.3 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}, T_J = 25 ^{\circ}\text{C}$ |       | 8     |          | ns       |  |
| Reverse Recovery Rise Time                    | t <sub>b</sub>            | 1                                                                                            |       | 7     | <u> </u> |          |  |

#### Notes:

- a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

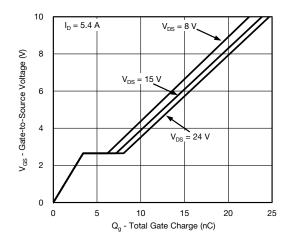




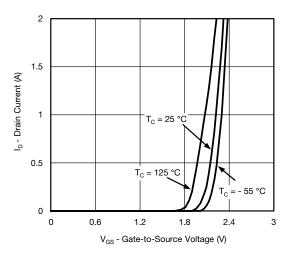
#### **Output Characteristics**



On-Resistance vs. Drain Current



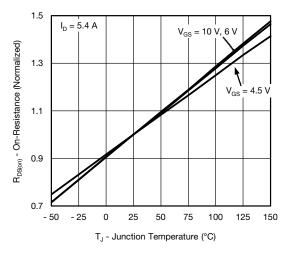
**Gate Charge** 



**Transfer Characteristics** 

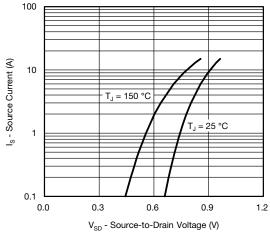


Capacitance

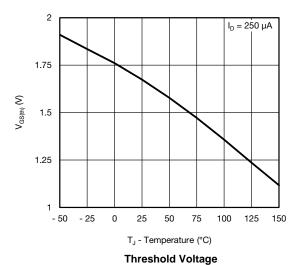


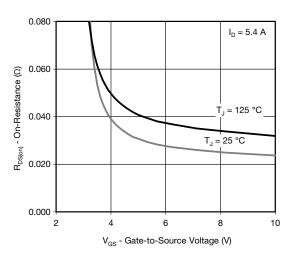
On-Resistance vs. Junction Temperature





## Source-Drain Diode Forward Voltage

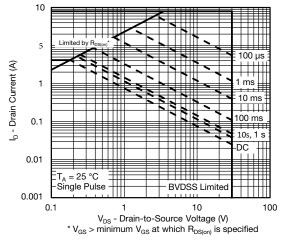




On-Resistance vs. Gate-to-Source Voltage



Single Pulse Power (Junction-to-Ambient)

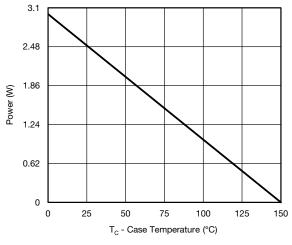


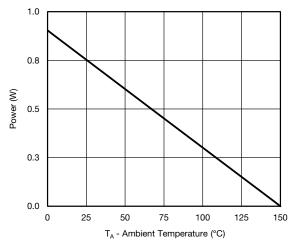
Safe Operating Area, Junction-to-Ambient





#### **Current Derating\***



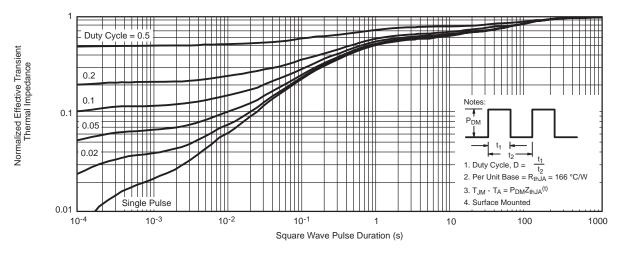


Power, Junction-to-Foot

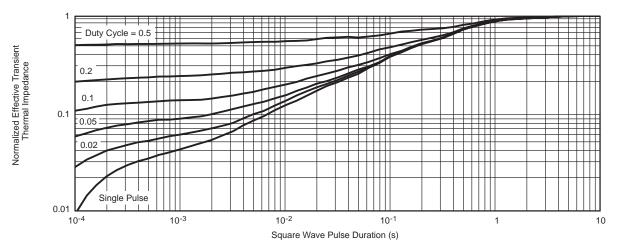
Power, Junction-to-Ambient

<sup>\*</sup> The power dissipation  $P_D$  is based on  $T_{J(max.)}$  = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.





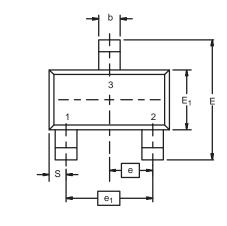
#### Normalized Thermal Transient Impedance, Junction-to-Ambient

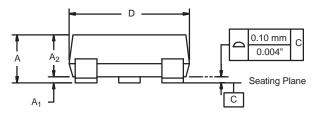


Normalized Thermal Transient Impedance, Junction-to-Foot



# SOT-23 (TO-236): 3-LEAD







| <b>Min</b><br>0.89 | Max                                                           | Min                                                                                    |                                                                                                                                                                                                                                                                                                                                                |  |
|--------------------|---------------------------------------------------------------|----------------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--|
| 0.80               |                                                               | IVIIII                                                                                 | Max                                                                                                                                                                                                                                                                                                                                            |  |
| 0.03               | 1.12                                                          | 0.035                                                                                  | 0.044                                                                                                                                                                                                                                                                                                                                          |  |
| 0.01               | 0.10                                                          | 0.0004                                                                                 | 0.004                                                                                                                                                                                                                                                                                                                                          |  |
| 0.88               | 1.02                                                          | 0.0346                                                                                 | 0.040                                                                                                                                                                                                                                                                                                                                          |  |
| 0.35               | 0.50                                                          | 0.014                                                                                  | 0.020                                                                                                                                                                                                                                                                                                                                          |  |
| 0.085              | 0.18                                                          | 0.003                                                                                  | 0.007                                                                                                                                                                                                                                                                                                                                          |  |
| 2.80               | 3.04                                                          | 0.110                                                                                  | 0.120                                                                                                                                                                                                                                                                                                                                          |  |
| 2.10               | 2.64                                                          | 0.083                                                                                  | 0.104                                                                                                                                                                                                                                                                                                                                          |  |
| 1.20               | 1.40                                                          | 0.047                                                                                  | 0.055                                                                                                                                                                                                                                                                                                                                          |  |
| 0.95 BSC           |                                                               | 0.0374 Ref                                                                             |                                                                                                                                                                                                                                                                                                                                                |  |
| 1.90 BSC           |                                                               | 0.0748 Ref                                                                             |                                                                                                                                                                                                                                                                                                                                                |  |
| 0.40               | 0.60                                                          | 0.016                                                                                  | 0.024                                                                                                                                                                                                                                                                                                                                          |  |
| 0.64 Ref           |                                                               | 0.025 Ref                                                                              |                                                                                                                                                                                                                                                                                                                                                |  |
| 0.50 Ref           |                                                               | 0.020 Ref                                                                              |                                                                                                                                                                                                                                                                                                                                                |  |
| 3°                 | 8°                                                            | 3°                                                                                     | 8°                                                                                                                                                                                                                                                                                                                                             |  |
|                    | 0.085<br>2.80<br>2.10<br>1.20<br>0.95<br>1.90<br>0.40<br>0.64 | 0.085 0.18 2.80 3.04 2.10 2.64 1.20 1.40 0.95 BSC 1.90 BSC 0.40 0.60 0.64 Ref 0.50 Ref | 0.085         0.18         0.003           2.80         3.04         0.110           2.10         2.64         0.083           1.20         1.40         0.047           0.95 BSC         0.0374           1.90 BSC         0.0748           0.40         0.60         0.016           0.64 Ref         0.025           0.50 Ref         0.020 |  |

DWG: 5479



## **RECOMMENDED MINIMUM PADS FOR SOT-23**



Recommended Minimum Pads Dimensions in Inches/(mm)



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